

60V P-Channel Enhancement Mode MOSFET

Voltage -60 V Current -1.9A

Features

- RDS(ON), VGS@-10V, ID@-1.9A<190mΩ
- RDS(ON), VGS@-4.5V, ID@-1.5A<240mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

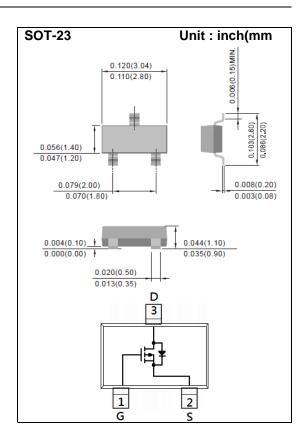
Mechanical Data

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams

Marking: A61



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-60	V	
Gate-Source Voltage		V _G s	<u>+</u> 20	V	
Continuous Drain Current	T _A =25°C		-1.9	А	
	T _A =70°C	l _D	-1.5		
Pulsed Drain Current (Note 1)		I _{DM}	-7.6	Α	
Power Dissipation	T _A =25°C	J	1.25	W	
	T _A =70°C	P _D	0.8		
Single Pulse Avalanche Energy (Note 5)		Eas	32	mJ	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal resistance - Junction to Ambient (Note 6)		Reja	100	°C/W	



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	BV _{DSS} V _{GS} =0V, I _D =-250uA		-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250uA -1.0		-1.88	-2.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-1.9A	-	140	190	mΩ	
		V _{GS} =-4.5V, I _D =-1.5A	-	190	240		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V, V _{GS} =0V	-	-	-1	uA	
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 7)							
Total Gate Charge	Q_g		-	8.3	-	nC	
Gate-Source Charge	Q_{gs}	V _{DS} =-30V, I _D =-1.9A, V _{GS} =-10V (Note 1,2)	-	1.8	-		
Gate-Drain Charge	Q_{gd}	VGS=-10V (1000 1,2)	-	1.6	-		
Input Capacitance	Ciss	\/ 20\/ \/ 0\/	-	430	-	pF	
Output Capacitance	Coss	V _{DS} =-30V, V _{GS} =0V, f=1.0MHZ	-	33	-		
Reverse Transfer Capacitance	Crss	I=I.UIVIMZ	-	29	-		
Turn-On Delay Time	td _(on)	\/ 00\/ I 40A	-	5.1	-		
Turn-On Rise Time	tr	V _{DD} =-30V, I _D =-1.0A,	-	20	-	ns	
Turn-Off Delay Time	td _(off)	V _{GS} =-10V, R _G =6Ω (Note 1,2)	-	36	-		
Turn-Off Fall Time	tf	RG=012 (Note 1,2)	-	11	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	I.				-1.5	A	
Diode Forward Current	Is		-				
Diode Forward Voltage	V_{SD}	Is=-1.0A, V _G s=0V	-	-0.78	-1.0	V	

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. The test condition is L=1mH, I_{AS}=8A, V_{DD}=25V, V_{GS}=10V
- 6. R@JA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 7. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

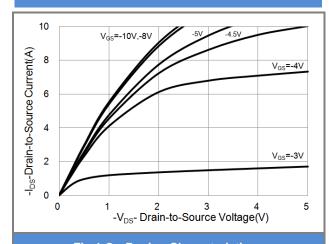


Fig.1 On-Region Characteristics

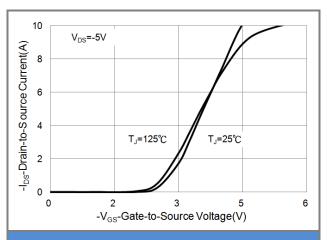


Fig.2 Transfer Characteristics

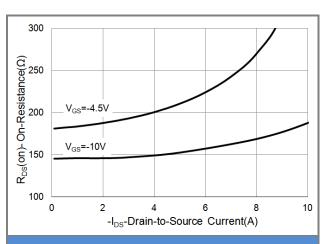


Fig.3 On-Resistance vs. Drain Current

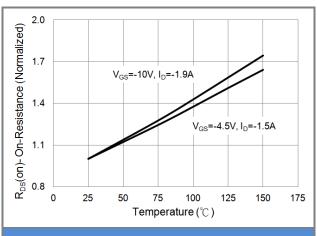


Fig.4 On-Resistance vs. Junction temperature

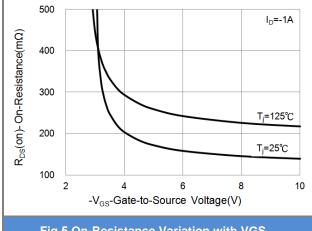
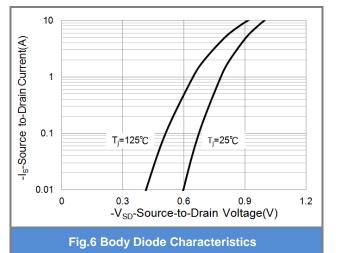


Fig.5 On-Resistance Variation with VGS.





TYPICAL CHARACTERISTIC CURVES

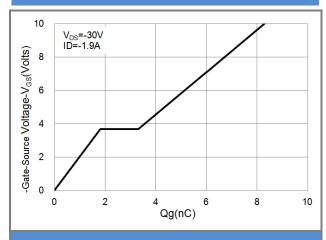


Fig.7 Gate-Charge Characteristics

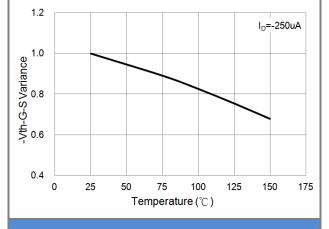


Fig.8 Threshold Voltage Variation with Temperature.

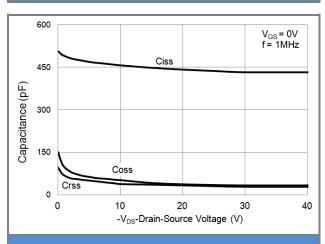


Fig.9 Capacitance vs. Drain-Source Voltage.

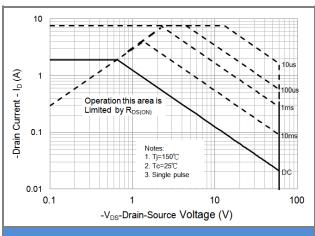


Fig.10 Maximum Safe Operating Area.

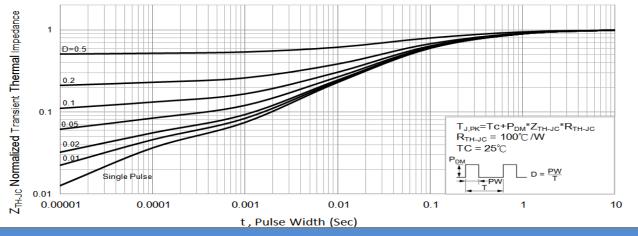


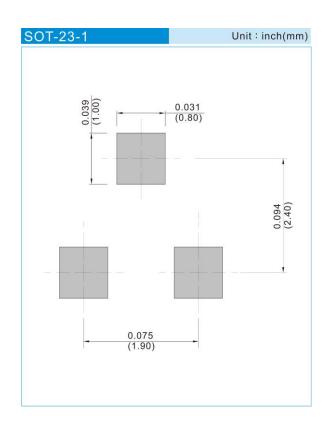
Fig.11 Normalized Transient Thermal Impedance vs. Pulse Width



Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJA3461	SOT-23	3K pcs / 7" reel	A61	

MOUNTING PAD LAYOUT





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